

BAL99, BAW56, BAV70, BAV99

TECHNICAL SPECIFICATIONS OF SURFACE MOUNT SWITCHING DIODES

VOLTAGE - 100 Volts

CURRENT - 0.15 Ampere

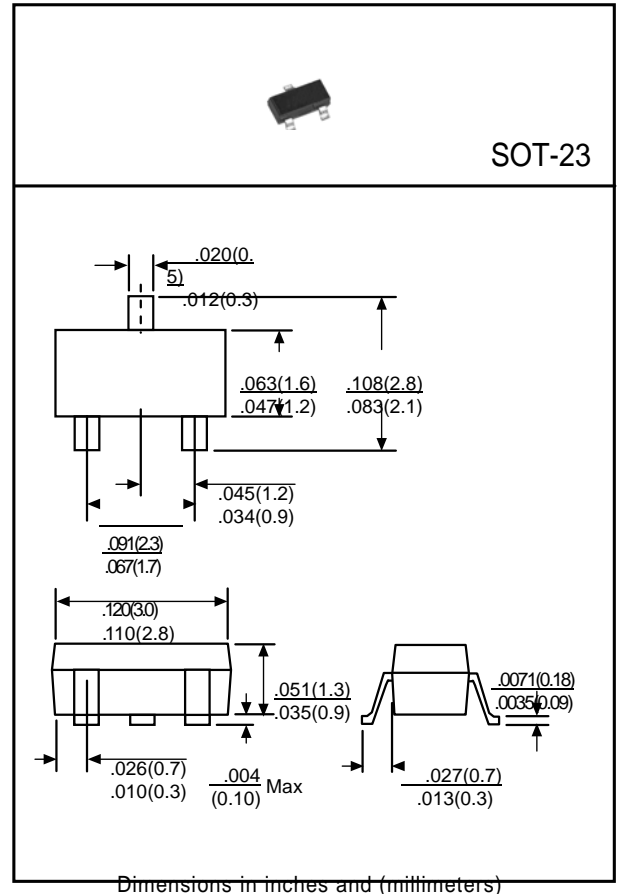
FEATURES

- * Surface Mount Package Ideally Suited for Automatic Insertion
- * Low power loss, high efficiency
- * Low leakage
- * Low forward voltage drop
- * High current capability

MECHANICAL DATA

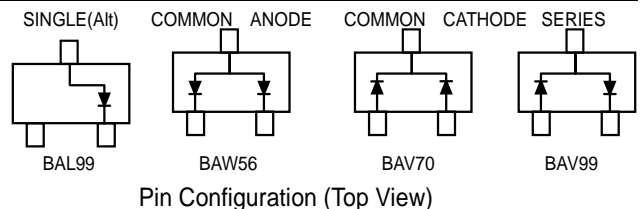
- * Case: Molded plastic
- * Epoxy: UL 94V-0 rate flame retardant
- * Terminals: Solder plated, solderable per MIL-STD-202E, Method 208 guaranteed
- * Mounting position: Any
- * Weight: 0.008 grams Approx.

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS
 Ratings at 25°C ambient temperature unless otherwise specified.
 Single phase, half wave, 60 Hz, resistive or inductive load.
 For capacitive load, derate current by 20%.



	SYMBOL	BAL99	BAW56	BAV70	BAV99	UNITS
Maximum Reverse Voltage	VR			75		V
Maximum Recurrent Peak Reverse Voltage	VRRM			100		V
Maximum Average Rectified Current	Io			150		mA
Peak Forward Surge Current, 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	IFSM			2.0		A
Maximum Power Dissipation Tamb=25°C	Ptot			350		mW
Maximum Forward Voltage (@IF=10mA)	VF			1.0		V
Maximum Reverse Current (@VR=VR Max)	IR			2.5		µA
Maximum Reverse Recovery Time(Note 1)	trr			6.0		nS
Typical Junction Capacitance(Note 2)	CJ			4.0		pF
Typical Thermal Resistance	RθJA			357		°C/W
Operating and Storage Temperature Range	TJ,TSTG			-55 to +125		°C

Note: 1. Test Conditions: IF=IR=10mA, RL=100Ω, VR=6V to IR=1mA, RL=100Ω
 2. Measured at 1MHz and VR=0



RATING AND CHARACTERISTIC CURVES (BAL99, BAW56, BAV70, BAV99)

FIG.1 - TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

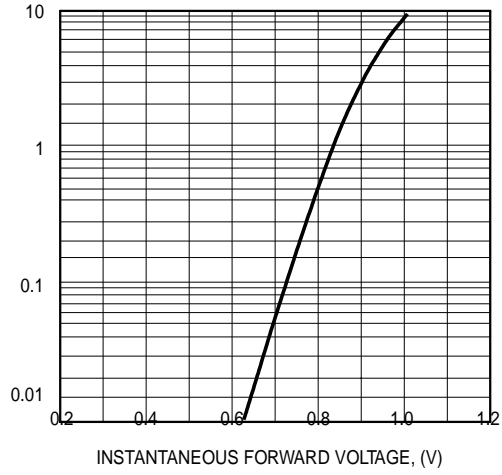


FIG.2 - TYPICAL REVERSE CHARACTERISTICS

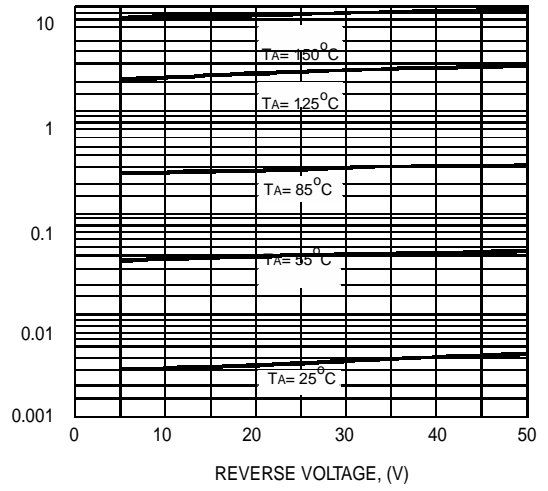


FIG.3 - TYPICAL JUNCTION CAPACITANCE

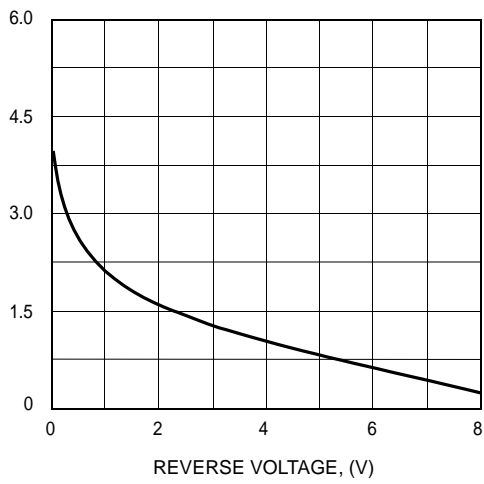


FIG.4 - RECTIFICATION EFFICIENCY MEASUREMENT CIRCUIT

